The LQ05041QCS6 is an ultimated efficient, 4 A rated integrated load switch with slew rate control. This remarkable device incorporates cutting-edge technology that achieves industryleading performance in terms of the lowest R_{ON}, quiescent current (I_D), and shutdown current (I_{SD}). A reduced R_{DN} minimizes conduction losses, and the low Io and Isp solutions empower designers to curtail parasitic leakage current, enhance system

The integration of slew rate control within the LQ05041QCS6 serves as a critical enhancement to system reliability, effectively mitigating voltage swings on the bus during switching events. In situations where uncontrolled switches might otherwise generate substantial inrush currents, leading to voltage droop and potential bus reset events, the slew rate control functions to confine inrush current during activation, thereby minimizing the voltage droop. The LQ05041QCS6 load switch device is designed in a chip scale

package of 0.97 mm x 1.47 mm x 0.55 mm with 6 bumps and 0.5 mm pitch and support an extensive input voltage range, enhancing

both the operational lifespan and the resilience of the system.

Additionally, this single device can serve in various voltage rail

applications, streamlining inventory management and lowering

LQ05041QCS6

5 V, 4 A, Ultra Low Consumption Load Switch With Slew Rate Control







Pinout Designation

Pin Description

Pin#

A1,B1

A2,B2

C1

C2

Pin

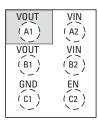
Name

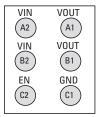
 V_{OUT}

 V_{IN}

GND

ΕN





Top View

Bottom View

0.97 mm x 1.47 mm x 0.55 mm WLCSP

Switch Input. Supply voltage for IC

Enable to control the switch

Description

Switch output

Ground

Features and Benefits

operational expenses.

- Low R_{ON} : 15 m Ω Typ @ 5.5 V_{IN}
- Ultra-low I₀: 3 nA Typ @ 5.5
- Ultra-low I_{sp}: 50 nA Typ @ 5.5
- I_{out} max: 4 A

Description

efficiency, and extend battery lifespan.

- Wide input range: 1.1 V to 5.5 V, 6 Vabs max
- Controlled rise time: 400 µs at 3.3 V_{IN}

- Internal EN pull-down resistor
- Integrated output discharge switch
- Wide operating temperature range: -40 °C ~ 85 °C
- HBM: 6 kV, CDM: 2 kV
- Ultra-small: 6 bumps in a 0.97 mm x 1.47 mm x 0.55 mm **WLCSP**

Applications

- Mobile devices
- Data storage, SSD
- IoT devices

1

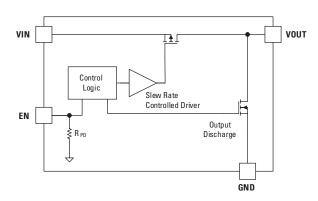
- Wearables
- Low power subsystems



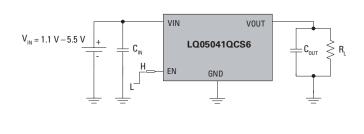


5 V, 4 A, Ultra Low Consumption Load Switch With Slew Rate Control

Functional Block Diagram



Typical Applications



Absolute Maximum Rating

Symbol	Par	Min	Max	Unit	
$V_{\rm IN}, V_{\rm OUT}, V_{\rm EN}$	Each Pin Volta	-0.3	6	V	
I _{OUT}	Maximum Contir		4	А	
P_{D}	Power Dissipa	ation at T _A = 25 °C		1.2	W
T_{STG}	Storage June	-65	150	°C	
T_{J}	Maximum Jur		150	°C	
$\theta_{\sf JA}$	Thermal Resistance, Junction to Ambie		85	°C/W	
ECD	Electrostatic Discharge Capability	Human Body Model, JESD22-A114	6		kV
ESD		Charged Device Model, JESD22-C101	2		kV

Note: Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions; extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Recommend Operating Conditions

Symbol	Parameter	Min	Max	Unit
V_{IN}	Supply Voltage	1.5	5.5	V
T_A	Ambient Operating Temperature	-40	85	°C

Note: The device is not guaranteed to function outside of the recommended operating conditions.



5 V, 4 A, Ultra Low Consumption Load Switch With Slew Rate Control

Electrical Characteristics ($V_{IN} = 1.1 \text{ V to } 5.5 \text{ V}$, typical values are at $V_{IN} = 3.3 \text{ V}$ and $T_A = 25 \,^{\circ}\text{C}$. Unless otherwise noted)

Symbol	Parameter	Test Co	Min	Тур	Max	Unit	
Basic Operati	ion						
V _{IN}	Supply Voltage			1.1		5.5	V
		EN = Enable, I _{OUT} = 0	$^{\circ}$ mA, $^{\circ}$		540		nA
Ι _α	Quiescent Current	EN = Enable, I _{OUT} = 0	$MA, V_{IN} = V_{EN} = 5.5 V^{1}$		3		nA
		EN = Enable, I _{OUT} = 0 mA, V	$T_{IN} = VEN = 5.5 \text{ V}, T_A = 85 ^{\circ}\text{C}^{1,5}$		10		nA
		EN = Disable, I _{out}	= 0 mA, V _{IN} = 1.1 V		9		nA
		EN = Disable, I _{out}		11		nA	
		EN = Disable, I _{OUT}	EN = Disable, $I_{OLIT} = 0$ mA, $V_{IN} = 3.3$ V				nA
I _{SD}	Shutdown Current	EN = Disable, I _{OUT}	= 0 mA, V _{IN} = 4.5 V		20		nA
		EN = Disable, I _{OUT}	= 0 mA, V _{IN} = 5.5 V		50	100	nA
		EN = Disable, I _{OUT} = 0 m	nA, V _{IN} = 5.5 V, T _A = 55 °C ⁵		250		nA
		EN = Disable, I _{OUT} = 0 m	1 A, $V_{IN} = 5.5 \text{ V}$, $T_{A} = 85 ^{\circ}\text{C}^{5}$		1.7		μΑ
	On-Resistance	V _{IN} = 5.5 V, I _{OUT} = 500 mA	T _A = 25 °C		15	17	mΩ
			T _A = 85 °C ⁵		17		mΩ
		VI _{IN} = 3.3 V, I _{OUT} = 500 mA	T _A = 25 °C		18	21	mΩ
R _{on}			T _A = 85 °C ⁵		21		mΩ
		$V_{IN} = 1.8 \text{ V}, I_{OUT} = 300 \text{ mA}$	T _A = 25 °C		28		mΩ
		$V_{IN} = 1.1 \text{ V, } I_{OUT} = 100 \text{ mA}$	T _A = 25 °C		55		mΩ
R _{DSC}	Output Discharge Resistance	E _N =Low , I _{FOBCF} = 10 mA			80	100	Ω
	ENIL AL CHELLAND	V _{IN} = 1.	.1 - 1.8 V	0.9			V
$V_{_{\mathrm{IH}}}$	EN Input Logic High Voltage	$V_{IN} = 1$.	V _{IN} = 1.8 - 5.5 V				V
	ENIL (I) I VII	$V_{IN} = 1$.	.1 - 1.8 V			0.3	V
V _{IL}	EN Input Logic Low Voltage	$V_{IN} = 1$.	8 - 5.5 V			0.4	V
R _{EN}	EN pull down resistance	E _N =	5.5 V	7	10.1	13	ΜΩ
I _{EN}	EN Current	E _N =	5.5 V			0.8	μΑ
Switching Ch	aracteristics	'					
t _{dON}	Turn-On Delay ²	D 450.0	0.1.5		250		μs
t _R	V _{out} Rise Time ²	$H_{OUT} = 150 \Omega$	$, C_{OUT} = 0.1 \mu F$		400		μs
t _{dON}	Turn-On Delay ^{2.5}	R _{out} = 500 Ω, C _{out} = 0.1 μF			240		μs
t _R	V _{OUT} Rise Time ^{3.4.5}				390		μs
t _{dOFF}	Turn-Off Delay ^{3.4.5}	D 40.0.0 5.1.5			0.4		μs
t _F	V _{out} Fall Time ^{3.4.5}	$R_{OUT} = 10 \Omega$,		1.5		μs	
t _{dOFF}	Turn-Off Delay ^{3.4.5}	D _ 500.0	C _ 0.1 uE		1.3		μs
t _F	V _{out} Fall Time ^{3.4.5}	$R_{OUT} = 500 \Omega$		16		μs	

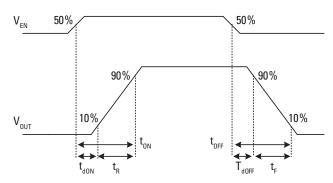
^{4.} Output discharge path is enabled during off.
5. By design; characterized, not production tested.



^{1.} $\rm I_{\rm Q}$ does not include enable pull down current through the pull-down resistor RPD.

^{2.} $t_{ON} = td_{ON} + t_{R}$ 3. $t_{OFF} = td_{OFF} + t_{F}$

Timing Waveforms



Typical Performance Characteristics

Figure 1 - On-Resistance vs. Supply Voltage

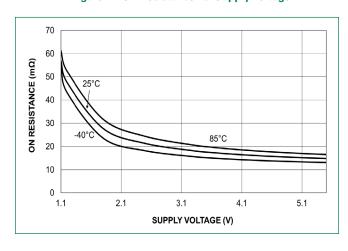


Figure 2 - On-Resistance vs. Temperature

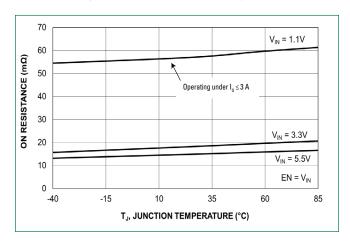


Figure 3 - Quiescent Current vs. Supply Voltage

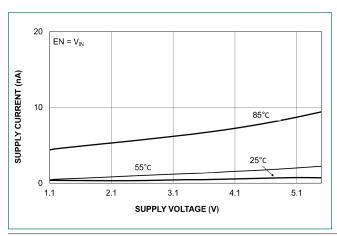
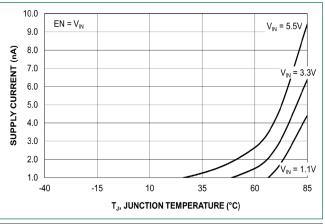


Figure 4 - Quiescent Current vs. Temperature





5 V, 4 A, Ultra Low Consumption Load Switch With Slew Rate Control

Figure 5 - Shutdown Current vs. Supply Voltage

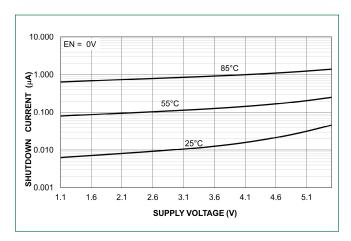


Figure 6 - Shutdown Current vs. Temperature

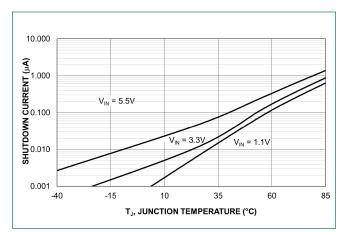


Figure 7 - EN Input Logic High Threshold

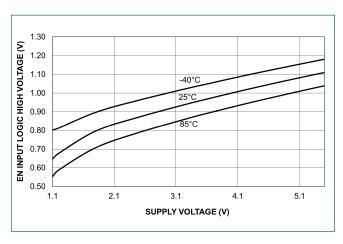


Figure 8 - EN Input Logic High Threshold Vs. Temperature

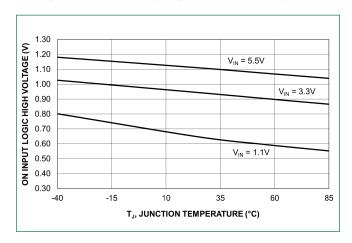


Figure 9 - EN Input Logic Low Threshold

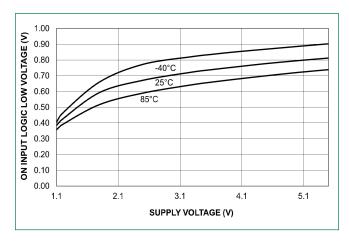
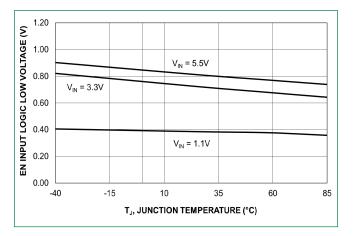


Figure 10 - EN Input Logic Low Threshold Vs. Temperature





5 V, 4 A, Ultra Low Consumption Load Switch With Slew Rate Control

Figure 11 - V_{OUT} Rise Time vs. Temperature

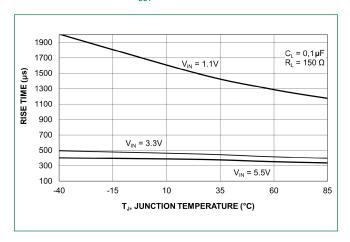


Figure 12 - Turn-On Delay Time vs. Temperature

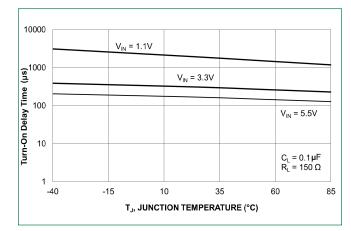


Figure 13 - V_{OUT} Discharge Resistance vs. Temperature

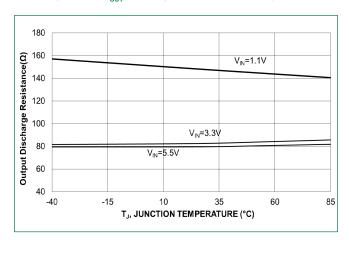


Figure 14 - Enable Pulldown Current vs. Temperature

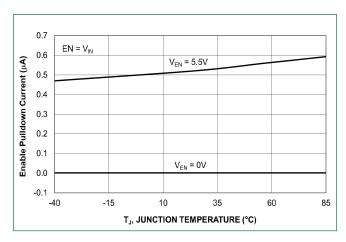


Figure 15 - Turn-On Response $V_{_{IN}}\!=3.3\,V,\,C_{_{IN}}\!=1.0~\mu\text{F},\,C_{_{OUT}}\!=0.1~\mu\text{F},\,R_{_{L}}=10~\Omega$

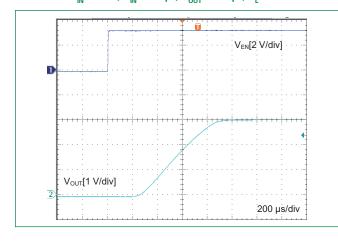
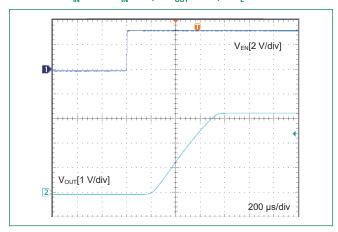


Figure 16 - Turn-On Response V $_{\text{IN}}$ =3.3 V, C $_{\text{IN}}$ =1.0 $\mu\text{F},$ C $_{\text{OUT}}$ = 0.1 $\mu\text{F},$ R $_{\text{L}}$ = 500 Ω





5 V, 4 A, Ultra Low Consumption Load Switch With Slew Rate Control

Application Information

The LQ05041QCS6 is a highly efficient integrated load switch with a 4 A capacity. It allows a fixed slew rate control to limit inrush current when activated. This device works with a wide input voltage range, from 1.1 V to 5.5 V, and has minimal on-resistance to reduce power loss. When it is off, it has very low leakage current, saving power resources. It is in a chip scale size package at 0.97 mm x 1.47 mm x 0.55 mm with 6 bumps at a 0.5 mm pitch make it ideal for efficient manufacturing in the space-saving required applications.

Input Capacitor

Although this is not required to have an input capacitor. Suggest to use a 0.1 µF capacitor positioned near the VIN pin to address voltage fluctuations on the input power rail that may occur as a result of transient inrush current during startup. To reduce the extent of the input voltage drop, suggest to use a higher input capacitor value.

Output Capacitor

An output capacitor is not mandatory for the LQ05041QCS6. Nevertheless, it is advisable to employ an output capacitor to minimize voltage undershoot on the output pin during switch-off.

Voltage undershoot may arise due to parasitic inductance from board traces or deliberate load inductances. In the presence of load inductances, utilizing an output capacitor can enhance output voltage stability and overall system reliability. Position the C_{OUT} capacitor in close proximity to the V_{OUT} and GND pins.

EN pin

The LQ05041QCS6 can be turned on by setting the EN pin to a high level. Be aware that there is an internal pull-down resistor in EN pin which can pull the primary switch to "off state" as long as no EN signal from an external controller is applied.

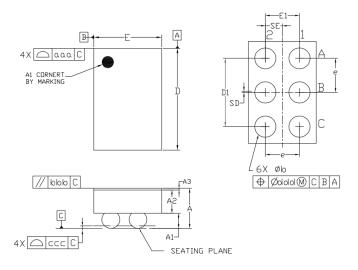
Output Discharge Function

The device incorporates an internal discharge N-channel FET switch located at the VOUT pin. When the EN signal switches the primary power FET to an off state, the N-channel switch activates to rapidly discharge the output capacitor.

Board Layout

To minimize the impact of parasitic inductance, it is advisable to keep all traces as short as possible. Using wider traces for V_{IN} , V_{OUT} , and GND is recommended to mitigate parasitic effects during dynamic operations and enhance thermal efficiency under high load currents.

Dimensions



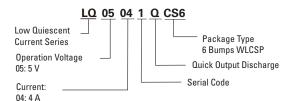
Millimeters								
Min	Nom	Max						
0.500	0.550	0.600						
0.225	0.250	0.275						
0.250	0.275	0.300						
0.020	0.025	0.030						
1.460	1.470	1.485						
0.960	0.970	0.985						
0.950	1.000	1.050						
0.450	0.500	0.550						
0.260	0.310	0.360						
	0.500 BSC							
	0.000 BSC							
	0.250 BSC							
Tol. of Form	& Position							
0.100								
0.100								
ccc 0.050								
ddd 0.050								
	0.500 0.225 0.250 0.020 1.460 0.960 0.950 0.450 0.260	Min Nom 0.500 0.550 0.225 0.250 0.250 0.275 0.020 0.025 1.460 1.470 0.960 0.970 0.950 1.000 0.450 0.500 0.260 0.310 0.500 BSC 0.250 BSC Tol. of Form & Position 0.100 0.100 0.050						

Millimeters



5 V, 4 A, Ultra Low Consumption Load Switch With Slew Rate Control

Part Numbering



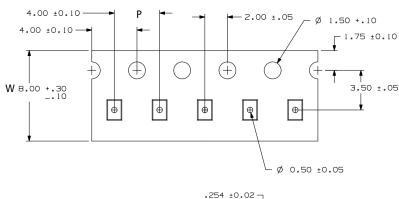
Part Marking

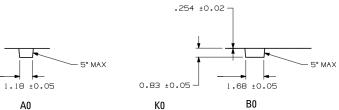


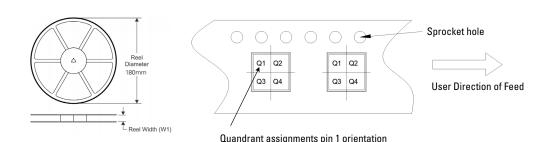
Pin 1 mark

BB = Device Code XX = Wafer Lot Run Code xx = Assembly Lot Run Code C = Assembly Code

Carrier Tape & Reel Specification







Dimensions are in millimeters

Device	Package	Pins	SPQ	Reel Diameter	Reel Width W1	A0	В0	КО	Р	w	Pin1
LQ05041QCS6	6 Bumps WLCSP	6	3000	180	9	1.18	1.68	0.83	4	8	Q1

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